Vishay General Semiconductor

High Current Density Surface Mount Trench MOS Barrier Schottky Rectifier

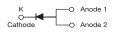
Ultra Low $V_F = 0.43$ V at $I_F = 5$ A

TMBS[®] eSMP[®] Series

www.vishay.com



TO-277A (SMPC)



PRIMARY CHARACTERISTICS				
I _{F(AV)}	12 A			
V _{RRM}	100 V			
I _{FSM}	200 A			
E _{AS}	100 mJ			
V_F at $I_F = 12 A$	0.58 V			
T _J max.	150 °C			
Package	TO-277A (SMPC)			
Diode variations	Single die			

TYPICAL APPLICATIONS

For use in low voltage high frequency inverters, freewheeling, DC/DC converters and polarity protection applications.

FEATURES

- Very low profile typical height of 1.1 mm
- Ideal for automatic placement
- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available
 Automotive ordering code; base P/NHM3
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

MECHANICAL DATA

Case: TO-277A (SMPC)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Base P/NHM3 - halogen-free, RoHS-compliant and AEC-Q101 gualified

Base P/NHM3_X - halogen-free, RoHS-compliant and AEC-Q101 qualified

("_X" denotes revision code e.g. A, B,....)

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test, HM3 suffix meets JESD 201 class 2 whisker test

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER	SYMBOL	V12P10	UNIT		
Device marking code		V1210			
Maximum repetitive peak reverse voltage	V _{RRM}	100	V		
Maximum average forward rectified current (fig. 1)	I _{F(AV)}	12	А		
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I _{FSM}	200	А		
Non-repetitive avalanche energy at I_{AS} = 2.0 A, T_{J} = 25 $^{\circ}\text{C}$	E _{AS}	100	mJ		
Peak repetitive reverse current at t_p = 2 µs, 1 kHz, T_J = 38 °C \pm 2 °C	I _{RRM}	1.0	А		
Operating junction and storage temperature range	T _J , T _{STG}	-40 to +150	°C		

HALOGEN FREE

Revision: 16-Dec-14

Document Number: 88981

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u> www.vishay.com

Vishay General Semiconductor

V12P10

ELECTRICAL CHARACTERISTICS ($T_A = 25$ °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Breakdown voltage	l _R = 1.0 mA	T _A = 25 °C	V _{BR}	100 (minimum)	-		
Instantaneous forward voltage	I _F = 5 A	- T _A = 25 °C	V _F ⁽¹⁾	0.50	-		
	I _F = 12 A			0.65	0.70	V	
	I _F = 5 A	T _A = 125 °C		0.43	-		
	I _F = 12 A			0.58	0.64		
Reverse current	V _B = 70 V	T _A = 25 °C	I _R ⁽²⁾	7.0	-	μA	
	v _R = 70 v	T _A = 125 °C		4.4	-	mA	
	V _R = 100 V	T _A = 25 °C		21.3	250	μA	
		T _A = 125 °C		11.8	20	mA	

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 $\,\%$ duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise specified)					
PARAMETER	SYMBOL	V12P10	UNIT		
Turpical thermal registering	R _{0JA} ⁽¹⁾	60	°C/W		
Typical thermal resistance	$R_{ ext{ heta}JL}$	3	0/10		

Note

⁽¹⁾ Units mounted on recommended PCB 1 oz. pad layout

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
V12P10-M3/86A	0.10	86A	1500	7" diameter plastic tape and reel		
V12P10-M3/87A	0.10	87A	6500	13" diameter plastic tape and reel		
V12P10HM3/86A (1)	0.10	86A	1500	7" diameter plastic tape and reel		
V12P10HM3/87A ⁽¹⁾	0.10	87A	6500	13" diameter plastic tape and reel		
V12P10HM3_A/H ⁽¹⁾	0.10	н	1500	7" diameter plastic tape and reel		
V12P10HM3_A/I (1)	0.10	I	6500	13" diameter plastic tape and reel		

Note

(1) AEC-Q101 qualified



Vishay General Semiconductor

RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)

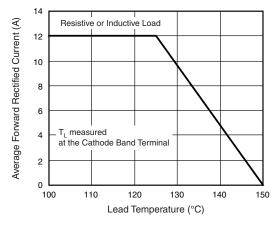


Fig. 1 - Maximum Forward Current Derating Curve

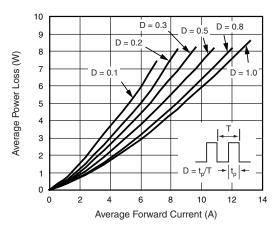


Fig. 2 - Forward Power Loss Characteristics

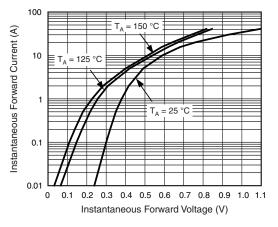


Fig. 3 - Typical Instantaneous Forward Characteristics

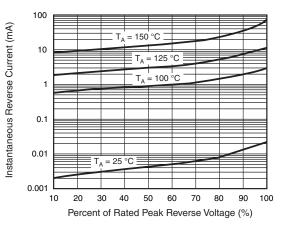


Fig. 4 - Typical Reverse Leakage Characteristics

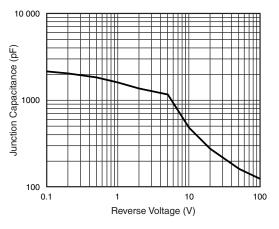


Fig. 5 - Typical Junction Capacitance

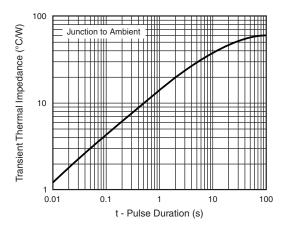


Fig. 6 - Typical Transient Thermal Impedance

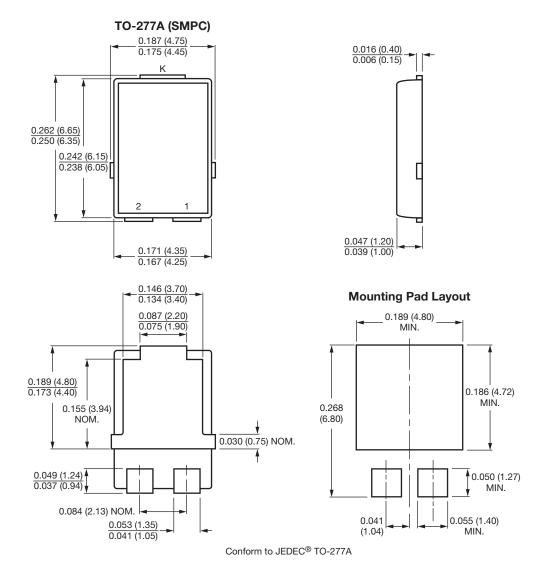
Document Number: 88981

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



Vishay General Semiconductor

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Vishay:

<u>V12P10HE3/86A</u> <u>V12P10-E3/86A</u> <u>V12P10-E3/87A</u> <u>V12P10HE3/87A</u> <u>V12P10-M3/87A</u> <u>V12P10-M3/86A</u> V12P10HM3/86A V12P10HM3/87A